

Vishay General Semiconductor

Surface Mount TRANSZORB[®] Transient Voltage Suppressors



PRIMARY CHARACTERISTICS					
V _{WM}	3.3 V				
P _{PPM}	100 W				
I _{FSM}	25 A				
T _J max.	150 °C				

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units specifically for protecting 3.3 V supplied sensitive equipment against transient overvoltages.

FEATURES

- Very low profile typical height of 0.65 mm
- Ideal for automated placement
- Oxide planar chip junction
- Uni-directional polarity only
- Peak pulse power: 100 W (10/1000 μs)
- ESD capability: 15 kV (air), 8 kV (contact)
- Meets MSL level 1, per J-STD-020C, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: MicroSMP

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free and RoHS compliant, commercial grade Base P/NHM3 - halogen-free and BoHS compliant

Base P/NHM3 - halogen-free and RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation	P _{PPM} ⁽¹⁾⁽²⁾	100	W			
Peak pulse current with a 10/1000 µs waveform (fig. 1)	I _{PPM}	13.7	А			
Peak pulse current with a 8/20 µs waveform (fig. 1)	I _{PPM}	75	А			
Non repetitive peak forward surge current 8.3 ms single half sine-wave	I _{FSM} ⁽²⁾	25	A			
Power dissipation T _L = 120 °C	P _D ⁽²⁾	1.0	W			
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150	°C			

Notes

⁽¹⁾ Non-repetitive current pulse, per fig. 1

⁽²⁾ Mounted on 6.0 mm x 6.0 mm copper pads to each terminal

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)											
DEVICE TYPE	DEVICE MARKING CODE	BREAKDOWN LEAN VOLTAGE CUR		EVERSE MAX. CLAN (AGE VOLTAGE / RENT AT I _{PPM} (10, 'V _{WM} µs)		E AT V _C 10/1000	T V _C MAX. CLAMPING		TYPICAL TEMPERATURE COEFFICIENT OF V _{BR}	TYP.JUNCTION CAPACITANCE C _J AT 0 V (1 MHZ)	
		v	mA	μA	v	v	Α	v	Α	(10 ⁻⁴ /°C)	pF
MSP3V3	KC	4.1	1.0	200	3.3	7.3	13.7	11.0	75	- 5.3	850



For technical questions within your region, please contact one of the following: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> **RoHS** COMPLIANT

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THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Typical thermal resistance	R _{0JA} ⁽¹⁾	125	°C/W			
	$R_{ ext{ hetaJL}}$ (1)	30	0/11			

Note

⁽¹⁾ Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 6.0 mm x 6.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band.

IMMUNITY TO STATIC ELECTRICAL DISCHARGE TO THE FOLLOWING STANDARDS

(T _A = 25 °C unless otherwise noted)								
STANDARD	TEST TYPE	TEST CONDITIONS	SYMBOL	CLASS	VALUE			
AEC-Q101-001	Human body model (contact mode)	C = 100 pF, R = 1.5 kW	M	H3B	> 8 kV			
IEC 61000-4-2 (2)	Human body model (air discharge mode) ⁽¹⁾	C = 150 pF, R = 150 W	V _C	4	> 15 kV			

Notes

 $^{(1)}\,$ Immunity to IEC 61000-4-2 air discharge mode has a typical performance $> 30\;kV$

(2) System ESD standard

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
MSP3V3-M3/89A	0.006	89A	4500	7" diameter plastic tape and reel			
MSP3V3HM3/89A ⁽¹⁾	0.006	89A	4500	7" diameter plastic tape and reel			

Note

⁽¹⁾ AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

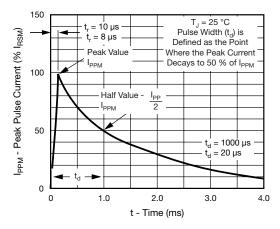


Fig. 1 - Pulse Waveform

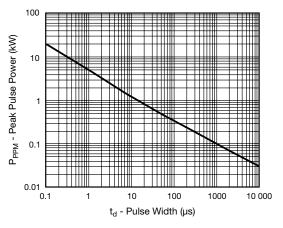


Fig. 2 - Peak Pulse Power Rating Curve



MSP3V3

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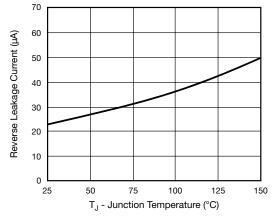


Fig. 3 - Relative Variation of Leakage Current vs. Junction Temperature

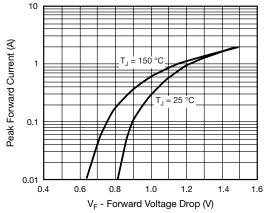
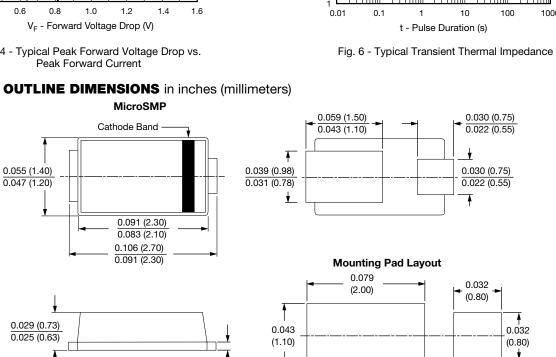


Fig. 4 - Typical Peak Forward Voltage Drop vs. Peak Forward Current





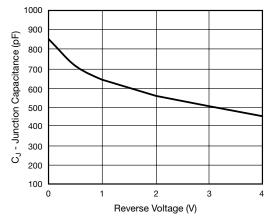
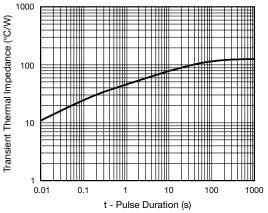


Fig. 5 - Typical Junction Capacitance



0.020 (0.50)

0.011 (0.27) 0.005 (0.12)



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